

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

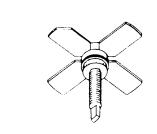
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MS1581

RF & MICROWAVE TRANSISTORS UHF TV/LINEAR APPLICATIONS

Features

- 860 MHz
- 25 VOLTS
- P_{OUT} = 4.0 WATTS
- $G_P = 7.0 \text{ dB MINIMUM}$
- GOLD METALLIZATION
- COMMON EMITTER CONFIGURATION

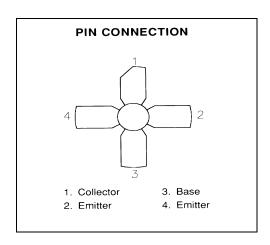


.280 4L STUD (M122)

epoxy sealed

DESCRIPTION:

The MS1581 is a silicon NPN bipolar transistor specifically designed for high linearity UHF TV driver applications. Gold metallization and emitter ballasting assure high reliability under Class A linear operation.



ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	45	V
V _{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter-Base Voltage	4	V
P _{DISS}	Power Dissipation	31.8	W
Ic	Device Current	1.6	Α
T J	Junction Temperature	+200	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Thermal Data

R _{TH(J-C)}	Thermal Resistance Junction-case	5.5	°C/W
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MS1581

ELECTRICAL SPECIFICATIONS (Tcase = 25°C) STATIC

Symbol	Test Conditions		Value			Unit	
		N	Min.	Typ.	Max.	Offic	
BV _{CBO}	I _C = 10 mA	$I_E = 0 \text{ mA}$		45		-	V
BV _{CEO}	I _C = 20 mA	I _E = 0 mA		25			٧
BV _{EBO}	I _E = 2.5 mA	I _E = 0 mA		3.0			V
I _{CBO}	V _{CB} = 28 V	I _E = 0 mA		-		0.9	mA
HFE	V _{CE} = 20 V	I _C = 500 mA		10		200	

DYNAMIC

Symbol	Test Conditions			Value			
Symbol			Min.	Typ.	Max.	Unit	
P _{out}	f = 860 MHz	$P_{IN} = 8 W$	$V_{CE} = 25 V$	4.0			w
G _P	f = 860 MHz	$P_{IN} = 8 W$	$V_{CE} = 25 \text{ V}$	7.0			dB
IMD ₃	P _{SYNC} = 4 W	$P_{IN} = 8 W$	$V_{CE} = 25 \text{ V}$			-60	dBc
Сов	f = 1 MHz	$V_{CB} = 25 \text{ V}$				20	pf

Conditions: $V_{CE} = 25 \text{ V}$ $I_C = 850 \text{ mA}$





PACKAGE MECHANICAL DATA

